NSN 5961-01-067-1066

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View Online at https://aerobasegroup.com/nsn/5961-01-067-1066

Inclosure Material:

Metal

Overall Length:

0.295 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

0.440 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

550.0 collector to base voltage, dc and 540.0 collector to emitter voltage, dc and 7.0 emitter to base voltage, dc

Current Rating Per Characteristic:

1.00 amperes source cutoff current

Power Rating Per Characteristic:

15.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: npn

Precious Material And Location:

Terminals and contact surfaces gold

Precious Material:

Gold

Test Data Document:

03640-6096879 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

